

New material cavity

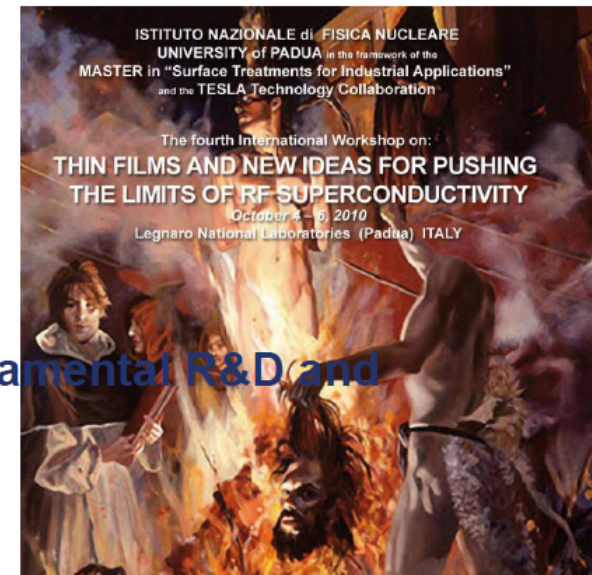
Grigory Ereemeev

Jefferson Lab

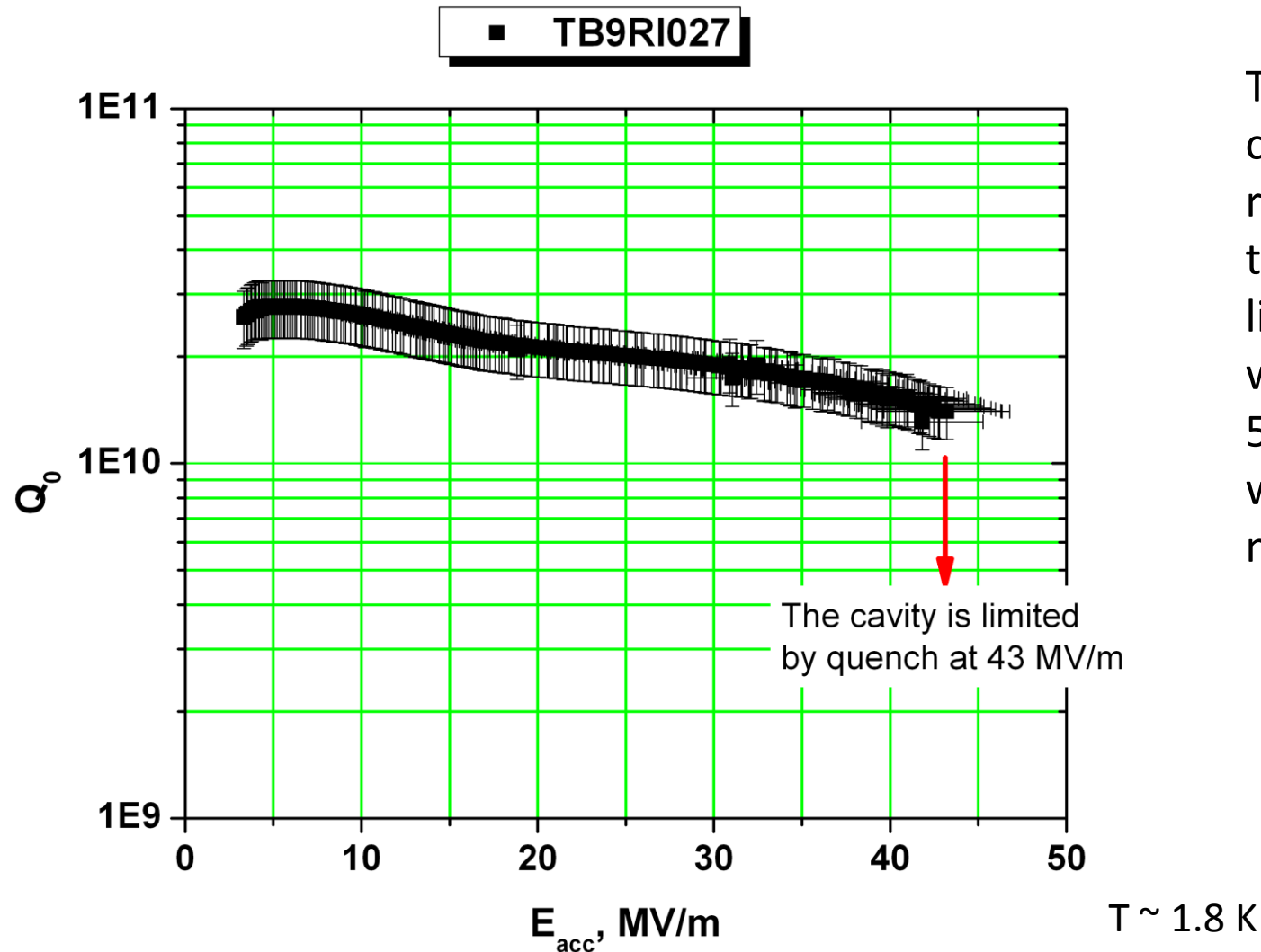
International Workshop on Linear Colliders 2010

October 18-22, 2010, CERN

- **Niobium**
 - 35-40 MV/m for TESLA shape cavities
 - 40-55 MV/m for LL, RE, LSF shape cavities
 - 60 MV/m seems upper limit w/ further material optimization
- **Material beyond niobium**
 - Many candidates on table
 - Growing interest
 - See talks from latest Thin Film Workshop
 - Youtube link <http://www.youtube.com/watch?v=vrl9H1Aajql>
 - Need to gap bridge between material fundamental R&D and cavity system development
 - Today we will hear two talks
 - ALD talk by Th. Prolier
 - New material cavity talk by G. Ereemeev



Motivation

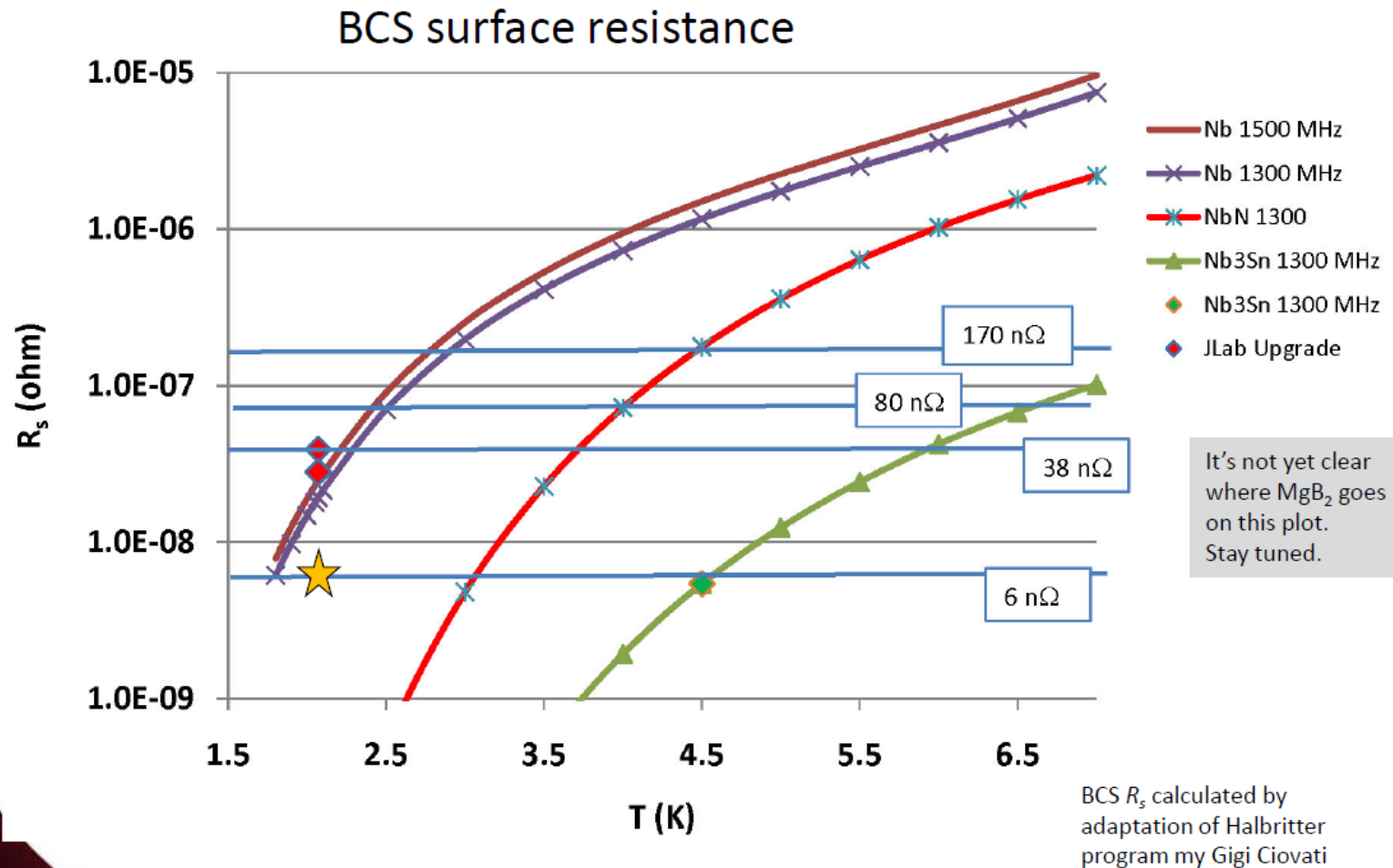


TESLA shaped cavities are reaching close to the fundamental limit of niobium, which should be ~ 50 MV/m. Hence, we have interest in new materials.

Possible Paths to $G \gg 50 \text{ MV/m}$

- Multilayers Nb/Nb₃Sn (NbN) Gurevich
- New high kappa materials
 - Nb₃Sn (most experience so far)
 - NbN
 - Best results 500 Oe at 10^{10} Q
 - MgB₂ (just starting, samples RF– no cavities)
 - RF measurements show rf losses do not rise until 700 Oe (Tajima/Tantawi)
 - HiTc (YBCO)
 - Very complex, short coherence length
 - Not recommended

The Landscape @ 1300 MHz



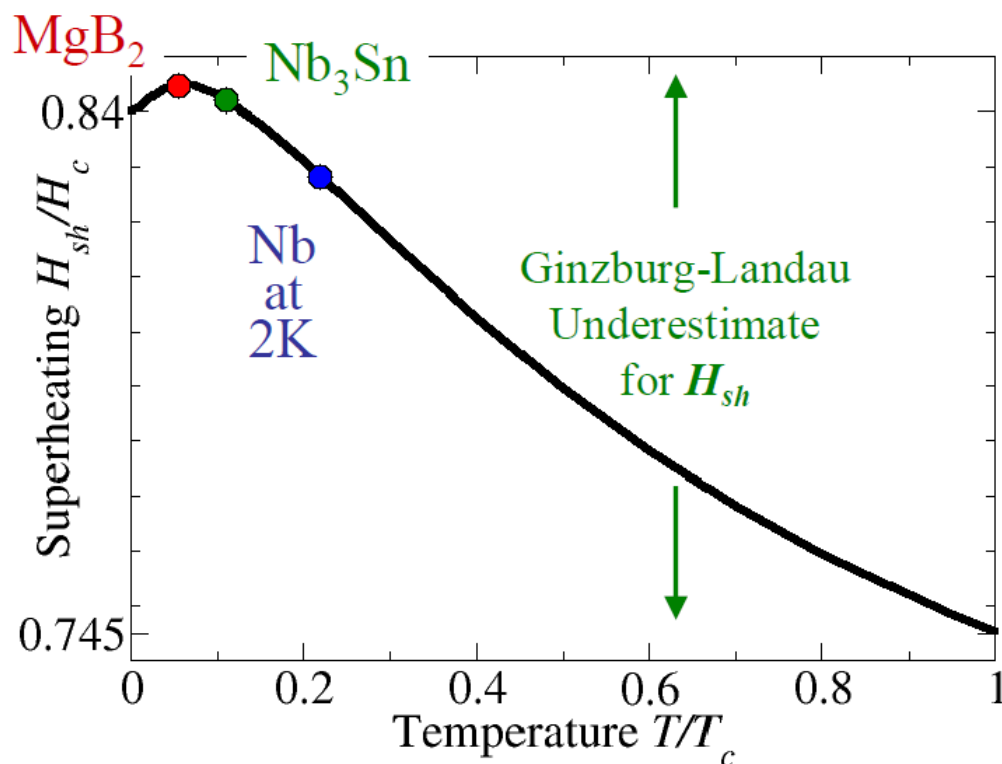
Sethna: 2007

Eilenberger (Pure BCS) Results !

Superheating field $H_{sh}(T)$ from the Eilenberger Equations

And large κ (so not applicable for Nb)

13% larger H_{sh} at low T than Ginzburg-Landau estimate !



Hrf-critical =
 $H_{sh} \sim 0.9 H_c$

Which means

G. Catelani and J. Sethna, "Temperature dependence of the superheating field for superconductors in the high- κ London limit," *Phys. Rev. B.*, 78 224509, 2008.

From presentation by
Hasan Padamsee at SRF
2009, Berlin

Theory gives hope for 100 – 200 MV/m !

- Eilenberger (BCS) theory predicts
- $E_{acc} \sim 120$ MV/m for perfect Nb₃Sn
- and 200 MV/m for perfect MgB₂ !!
- This is a strong motivation for materials and cavity push
- But be prepared for a long road to realization..
- Remember how long we took for Nb to reach 30 MV/m..starting in 1965 ! – 45 years
- Can we do it? Where are we now?

The best results with new materials

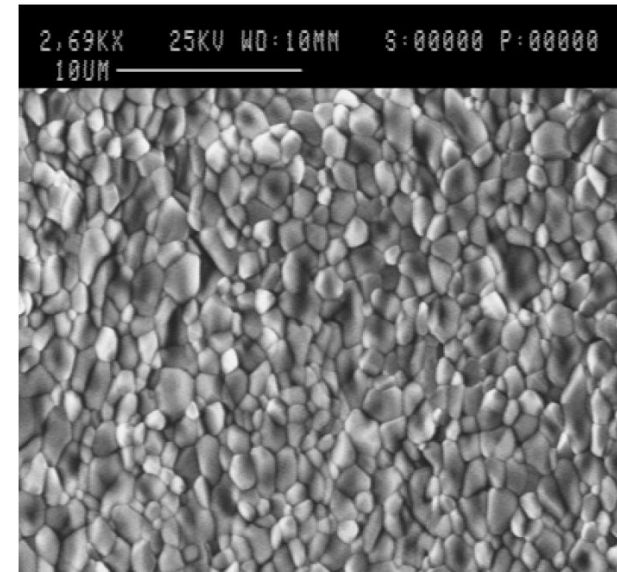
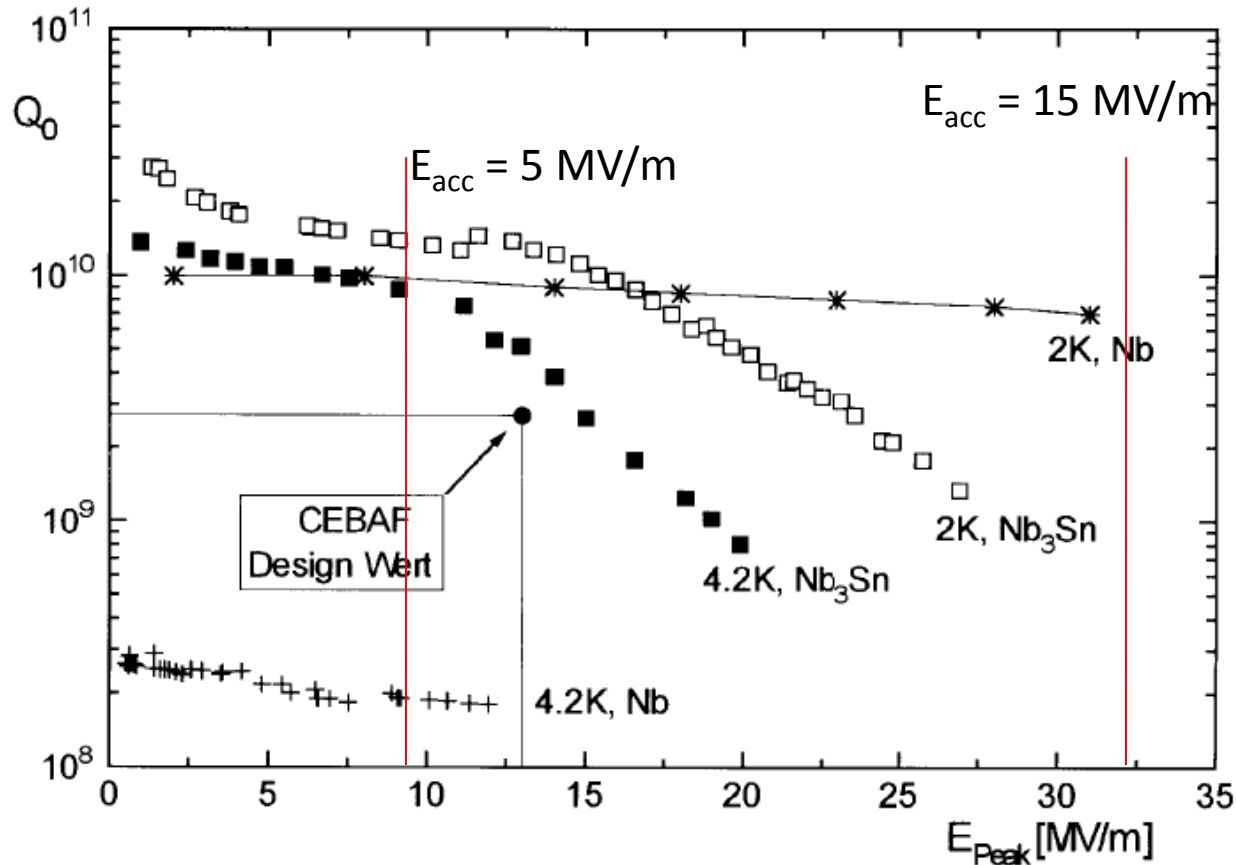
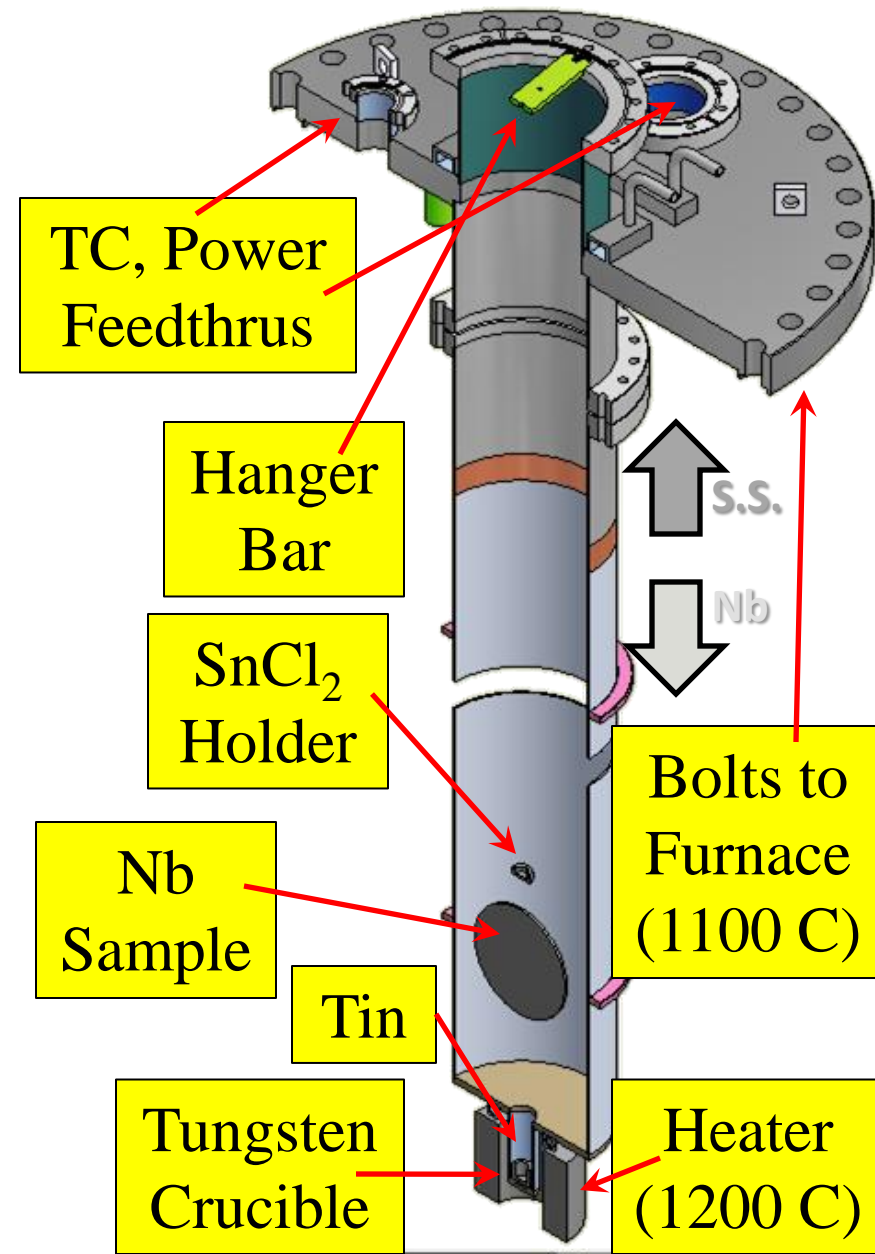


Fig. 2: SEM picture of a typical Nb₃Sn surface as grown for 3h on a high purity Nb sample.

G. Müller, P. Kneisel, D. Mansen, H. Piel, J. Puoryamout, and R. W. Röth. Nb₃Sn layers on high-purity Nb cavities with very high quality factors and accelerating gradients. In S. Myers, A. Pacheco, R. Pascual, C. Petit-Jean-Genaz, and J. Poole, editors, *Proceedings of the 1996 European Particle Accelerator Conference*, pp. 2085–2087, Barcelona, Spain, 1996.

Cornell Nb₃Sn Furnace Insert

- Vapor diffusion coating method from Wuppertal
- Crucible of Sn is heated in an evacuated chamber
- Evaporated tin coats Nb sample in the chamber
- Insert is compatible with existing UHV furnace
- SnCl₂ nucleates growth
- Independently control Nb, Sn temperatures

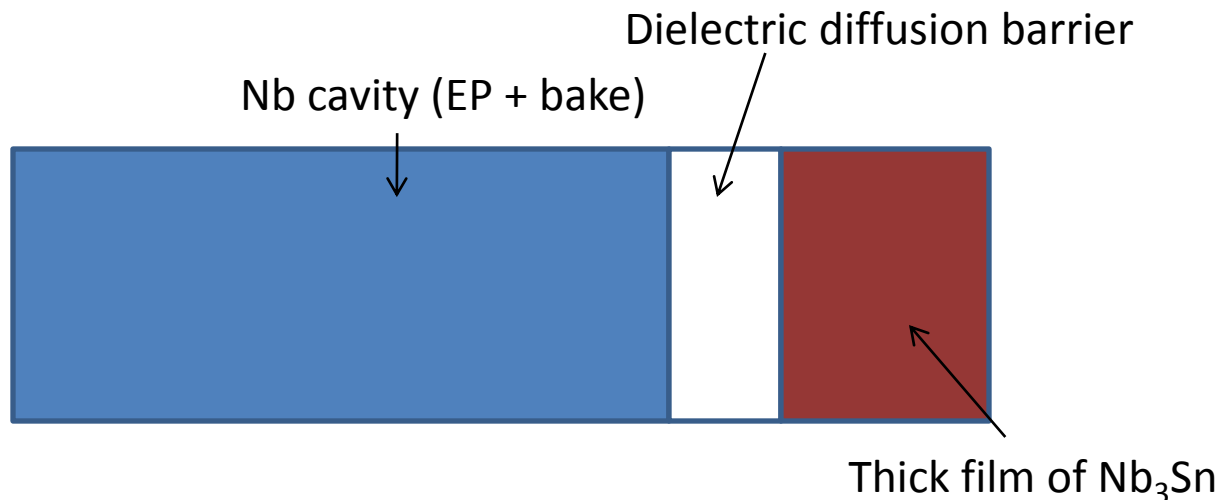


Outlook and Plans

- Characterize Nb₃Sn coatings with surface studies
- Measure RF performance with Cornell TE cavities
- All parts obtained for insert, and machining almost done; hope to start coating mid-November
- Once process parameters optimized, coat cavities
- Use thermometry and Cornell OST quench detection to locate any weak areas in coating during RF tests
- Dissect cavities so that surface studies can be performed on weak areas
- Use this feedback to improve coating technique

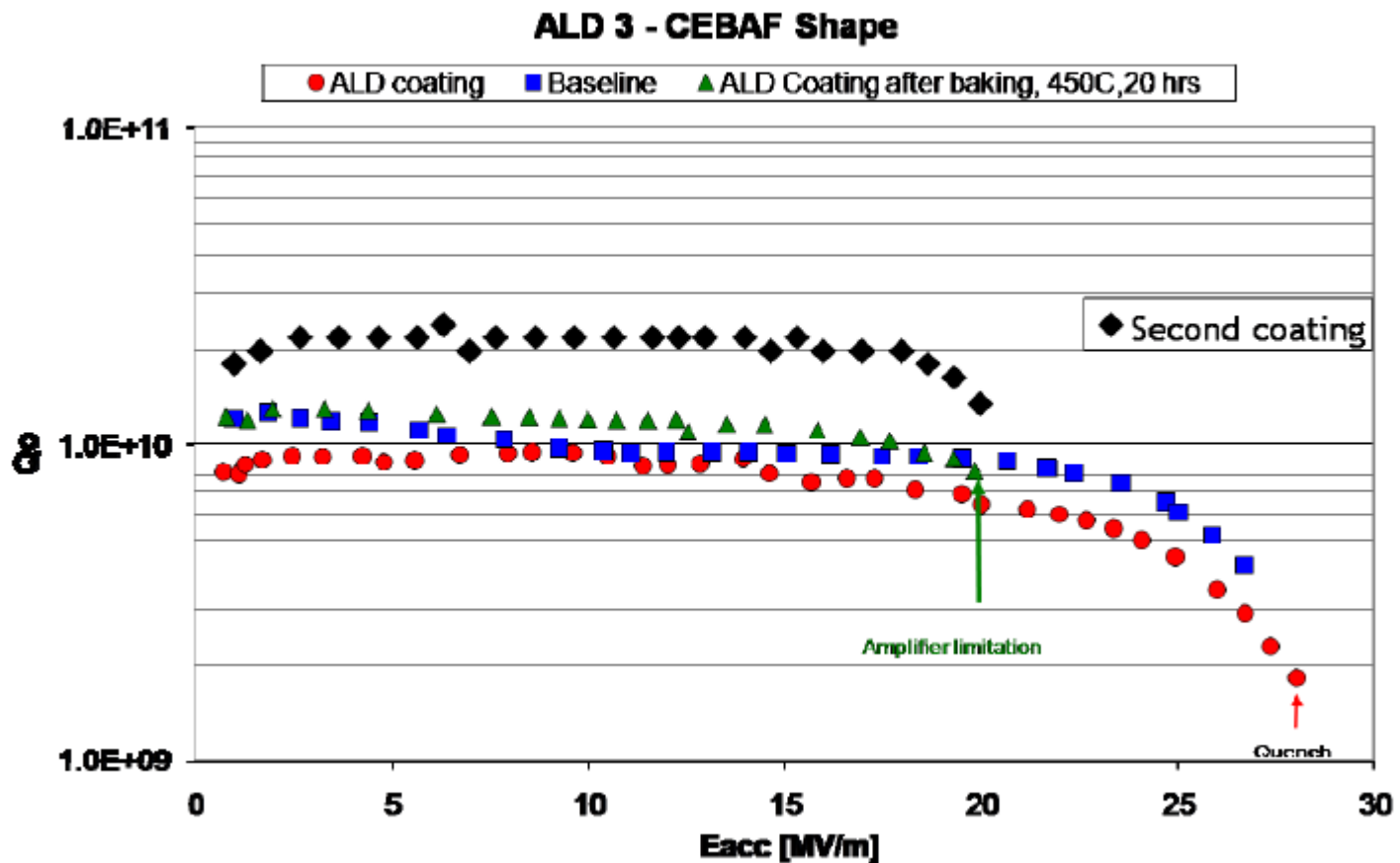
New material cavity at JLab

- We also would like to coat a cavity with Nb_3Sn with good control and flexibility over coating parameters, because superconducting properties depends crucially on stoichiometry: from 18 to 25 at. % Sn, the superconducting transition temperature of Nb_3Sn changes from about 6 K to 18.3 K, and its upper critical field from 6 T to 30 T
- Therefore, the idea is **to stabilize the optimal stoichiometry by creating a dielectric diffusion barrier between the niobium substrate and Nb_3Sn film**



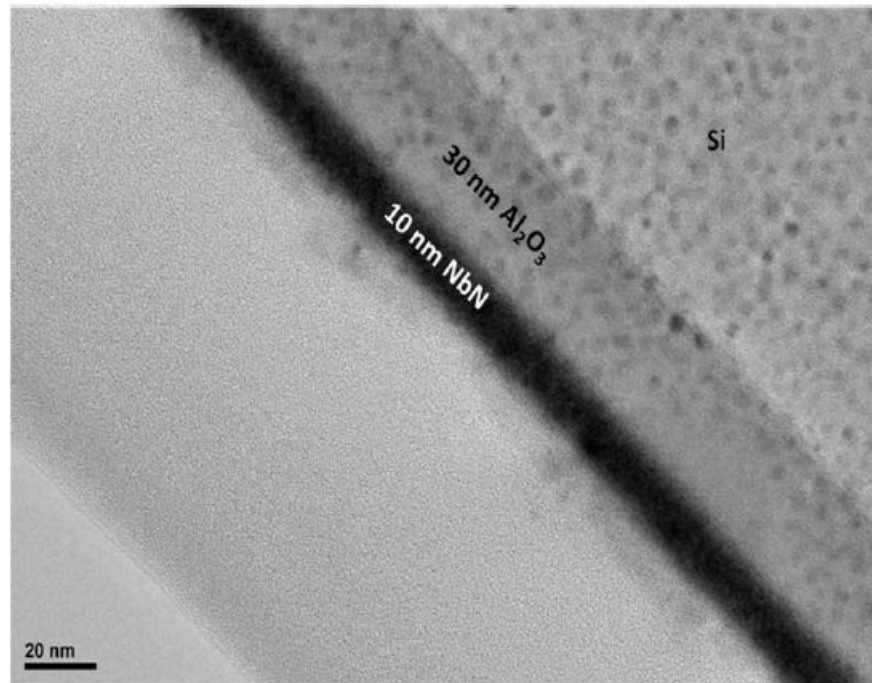
New material cavity at JLab

- Atomic Layer Deposition technique seems to be the best approach to creating a dielectric diffusion barrier



Th. Proslier et al., Proceedings of PAC09, Vancouver, BC, Canada

Cross-sectional TEM Analysis of ALD NbN Film



Cross-sectional TEM image showing a 10 nm ALD NbN thin film deposited on a Si substrate with 30 nm ALD Al₂O₃ film. The ALD NbN film has similar structure as shown in Figure 3 exhibiting NbN crystallites surrounded by amorphous NbN because the film was deposited at 450 °C. Furthermore superconductor-insulator (S-I-S) multilayers were realized by ALD. The TEM micrograph demonstrates that an ALD NbN film was successfully deposited onto ALD Al₂O₃ on Si substrates.



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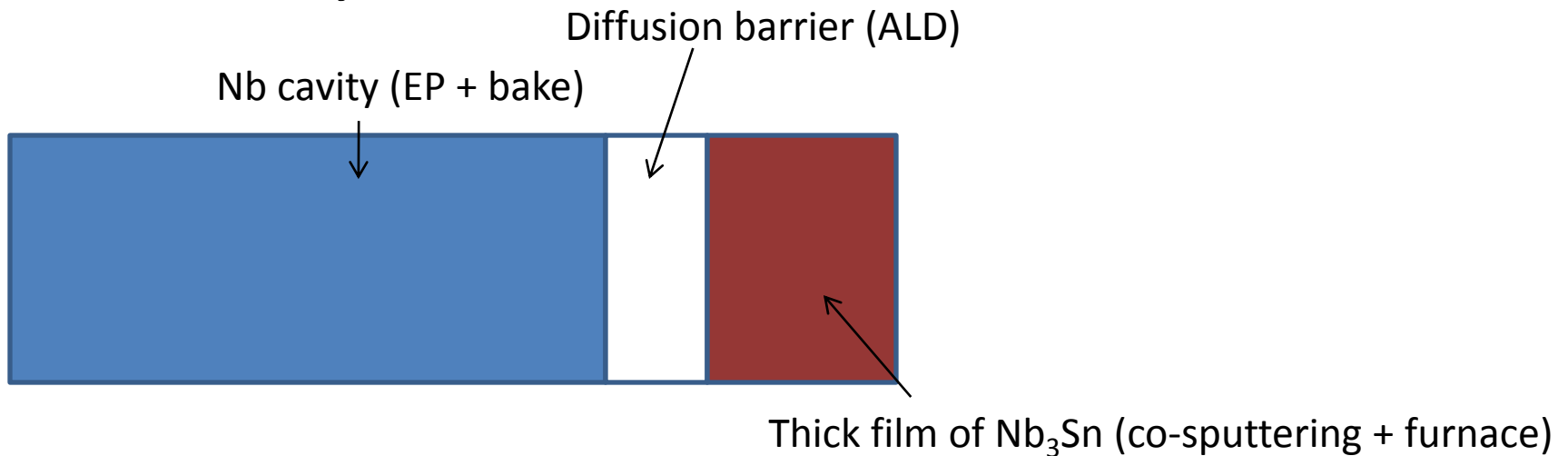
Diefeng Gu et al., SRF Thin Film Wkshp – Oct 2010

New material cavity at JLab

- Sputtering seems to be the best approach to deposit Nb and Sn on SRF cavity surface
- After sputtering, apply annealing in order to achieve the desirable phase

New material cavity at JLab

- Ideally, we would like to built a system specifically design for 1.3 ILC cavity ALD and sputtering coating. This will allow control and flexibility.



Timeline

1 st year	Identify critical parameters for ALD and sputtering systems, and design ALD and sputtering systems around those parameters to coat SRF cavity
2 st year	Build ALD and sputtering systems
3 st year	Commissioning and studies of coated samples with RF and surface studies techniques
4 st year	Studies of coated samples with RF and surface studies techniques, studies of coated cavities with RF and thermometry, cavity dissections studies
5 st year	Studies of coated cavities with RF and thermometry, cavity dissections studies

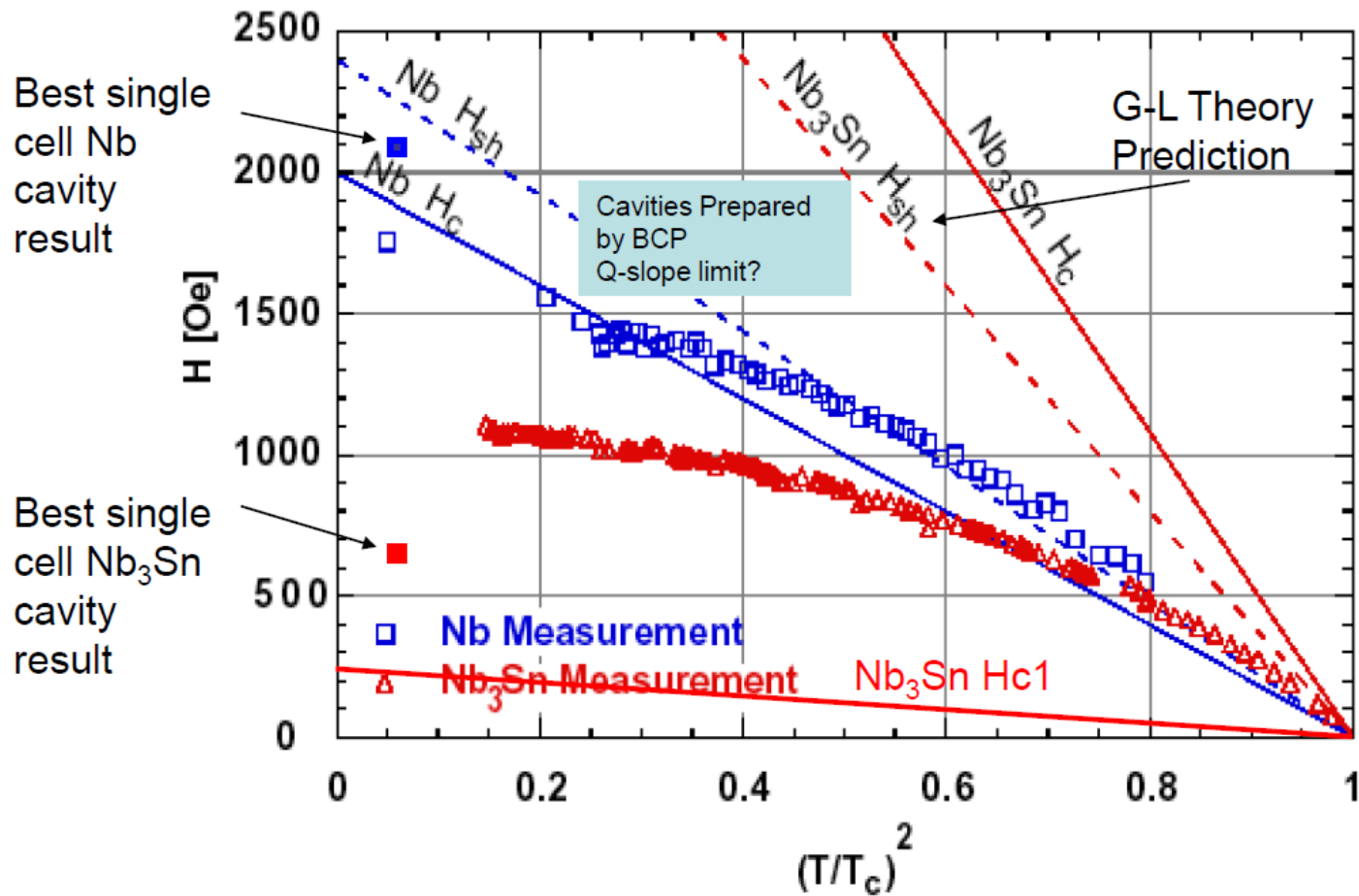
Closing remarks

- New materials is a high risk, but also high reward approach to gradients above 50 MV/m
- Nb₃Sn is the best studied new materials, but we still need a systematic study of this compound in SRF cavities
- It is essential to perform such a study on real SRF cavities in order to get values of interest: residual resistance, field dependence of RF resistance, and limiting fields!!

THANK YOU!

Pulsed Measurements Encouraging
Measured RF Critical Field for : Nb₃Sn Using High Pulse Power
(Calibrated results with Nb)

Important: H_{rf}-crit for Nb₃Sn > H_{c1}..

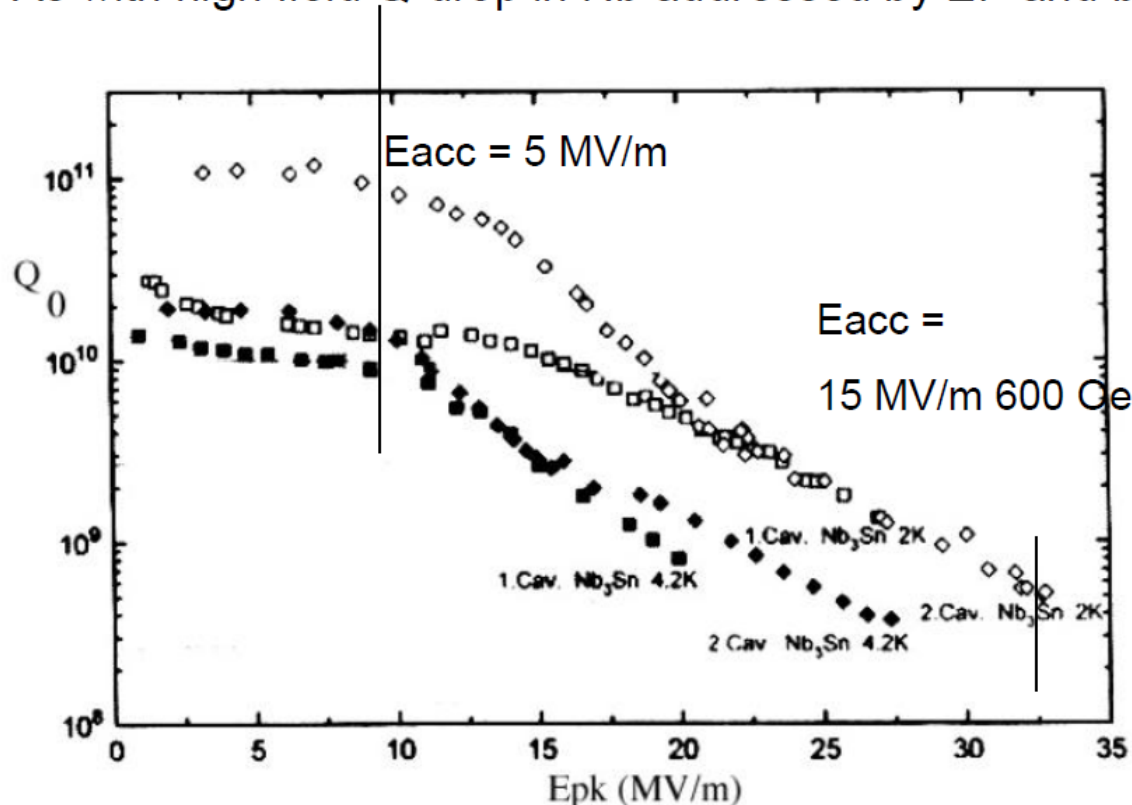


From presentation by Hasan Padamsee at SRF 2009, Berlin

Best CW Result for Single Cell Nb₃Sn

Cavity 1300 MHz (Mueller and Kneisel)

- Q-slope observed in CW measurements may be addressed by improved material preparation
- As with high field Q-drop in Nb addressed by EP and baking.



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